Retriggerable Monostable Multivibrator

HITACHI

ADE-205-699 (Z)

Preliminary Rev.0 Jul. 2002

Description

The HD74LV2GT123A features output pulse duration control by three methods. In the first method, the \overline{A} input is low and the B input goes high. In the second method, the B input is high and the \overline{A} input goes low. In the third method, the \overline{A} input is low, the B input is high, and the clear (\overline{CLR}) input goes high. The basic pulse duration is programmed by selecting external resistance and capacitance values. The external timing capacitor must be connected between Cext and Rext/Cext (positive) and an external resistor connected between Rext/Cext and V_{cc}. To obtain variable pulse durations, connect an external variable resistance between Rext/Cext and V_{cc}. Once triggered, the basic pulse duration can be extended by retriggering the gated low level active (\overline{A}) or high level active (B) input. Pulse duration can be reduced by taking \overline{CLR} low. The output pulse equation is simply : $t_{wo} = Cext \bullet Rext$.

Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

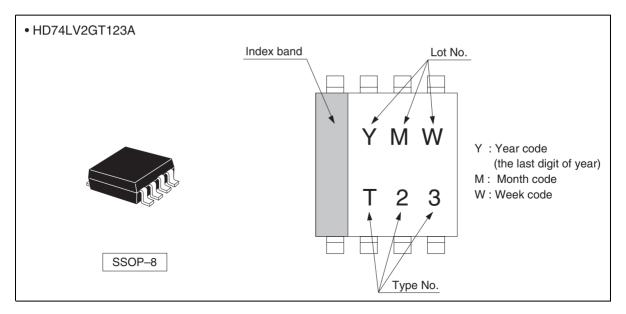
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Control input is TTL compatible input level. Supply voltage range : 4.5 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V) All outputs V_0 (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current $\pm 12 \text{ mA} (@V_{cc} = 4.5 \text{ V to } 5.5 \text{ V})$
- All the logical inputs have hysteresis voltage for the slow transition.
- Package type

Package type	Package code	Package suffix	Taping code
SSOP-8 pin	TTP-8DBV	US	E (3,000 pcs / Reel)



Outline and Article Indication



Function Table

Inputs		Output Q		
CLR	Ā	В		
L	Х	Х	L	
Н	Н	Х	L	
Н	Х	L	L	
Н	L	\uparrow	л	
Н	\downarrow	Н	л	
\uparrow	L	Н	л	

H : High level

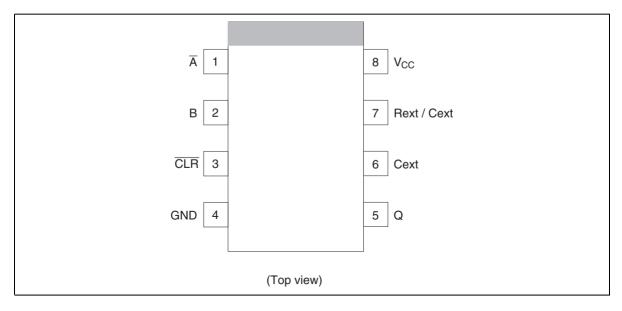
L : Low level

X : Immaterial

 \uparrow : Low to high transition

 \downarrow : High to low transition

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	–0.5 to 7.0	V	
Input voltage range ¹	V	-0.5 to 7.0	V	
Output voltage range *1, 2	V _o	–0.5 to V _{cc} + 0.5	V	Output : H or L
		-0.5 to 7.0		V _{cc} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	Ι _{οκ}	±50	mA	V_{o} < 0 or V_{o} > V_{cc}
Continuous output current	I _o	±25	mA	$V_{o} = 0$ to V_{cc}
Continuous current through V_{cc} or GND	$I_{\rm cc}$ or $I_{\rm gnd}$	±50	mA	
Maximum power dissipation at Ta = 25° C (in still air) ³	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 5.5 V maximum.

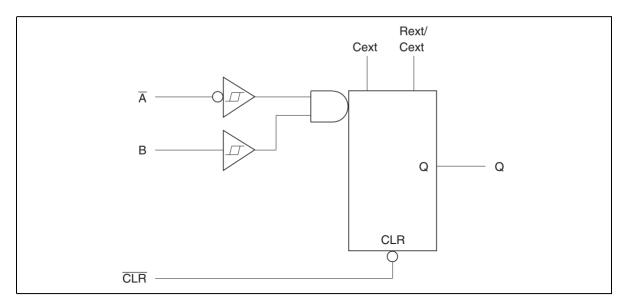
3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Item	Symbol	Min	Тур	Max	Unit	Conditions
Supply voltage range	V _{cc}	4.5	_	5.5	V	
Input voltage range	V,	0	_	5.5	V	
Output voltage range	Vo	0	_	V _{cc}	V	
Output current	I _{он}	_	_	-12	mA	V_{cc} = 4.5 to 5.5 V
	I _{ol}	_	_	12	_	V_{cc} = 4.5 to 5.5 V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	_	20	ns / V	$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
External timing registance	Rext	1	_		kΩ	V_{cc} = 4.5 to 5.5 V
External capacitance	Cext	_	Unlimited	_	F	
Supply transition rise rate	Δt / ΔV_{cc}	1	_	_	ms / V	
Operating free-air temperature	T _a	-40		85	°C	

Recommended Operating Conditions

Note: Unused or floating inputs must be held high or low.

Logic Diagram



Electrical Characteristic

• Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{cc} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	4.5 to 5.5	2.0	_	_	V	
	V	4.5 to 5.5		_	0.8		
Hysteresis voltage	V _H	5.0	_	0.15	_	V	$V_{T}^{+} - V_{T}^{-}$
Output voltage	V _{OH}	Min to Max	V _{cc} -0.1	_	_	V	I _{он} = -50 μA
		4.5	3.8	_	_		I _{он} = –12 mA
	V _{ol}	Min to Max	_	_	0.1		I _{oL} = 50 μA
		4.5	_	_	0.55		I _{oL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Input current Rext / Cext	I _{IN}	5.5	_	—	±2.5	μA	$V_{IN} = V_{CC}$ or GND
Quiescent supply current	I _{cc}	5.5	_	—	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
Active state	ΔI_{cc}	4.5		_	650	μA	$V_{IN} = V_{CC}$ or GND
supply current		5.5		_	975		Rext / Cext = $0.5V_{cc}$
Output leakage current	I _{off}	0	_	_	5	μΑ	$V_{_{\rm IN}}$ or $V_{_{\rm O}}$ = 0 to 5.5 V
Input capacitance	C _{IN}	5.0		3.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

•	V _{cc}	=	5.0	±	0.5	V
-	• CC	_	5.0	÷	0.5	•

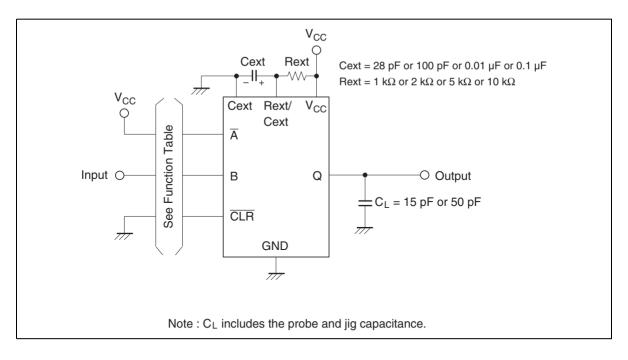
Item	Symbol	T _a = 2	5°C		$T_a = -40$ to $85^{\circ}C$		Unit	Test	FROM	то
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{plH}	_	7.3	12.0	1.0	14.0	ns	$C_{L} = 15 \text{ pF}$	\overline{A} or B	Q
delay time	t _{PHL}	_	8.5	14.0	1.0	16.0	_	$C_{L} = 50 \text{ pF}$	-	
Enable time	t _{zH}	_	5.9	9.4	1.0	11.0	ns	$C_{L} = 15 \text{ pF}$	CLR	Q
	t _{zL}	—	7.5	11.4	1.0	13.0	_	$C_{L} = 50 \text{ pF}$	-	
Disable time	t _{HZ}	_	7.3	12.9	1.0	15.0	ns	$C_{L} = 15 \text{ pF}$	CLR	Q
	t _{LZ}	_	8.7	14.9	1.0	17.0		$C_{L} = 50 \text{ pF}$	(Trigger)	
Output pulse width	t _{wa}	—	140	200	—	240	ns	$C_{L} = 50 \text{ pF},$ Cext = 28 pF	⁻ , Rext = 2	2 kΩ
		90	100	110	90	110	μs	$C_{L} = 50 \text{ pF},$ Cext = 0.01	μF, Rext =	= 10 kΩ
		0.9	1.0	1.1	0.9	1.1	ms	$C_{L} = 50 \text{ pF},$ Cext = 0.1 μ	F, Rext =	10 kΩ
Pulse width	t _w	5.0	_	_	5.0	_	ns	\overline{A} , B or \overline{CLR}		
Retrigger time	et _{rr}	—	20	—	—	—	ns	\overline{A} or B (Rext = 1 k Ω	2, Cext = 1	00 pF)
			0.95	—	—	—	μs	Ā or B (Rext = 1 kΩ	2, Cext = 0	0.01 μF)

Operating Characteristics

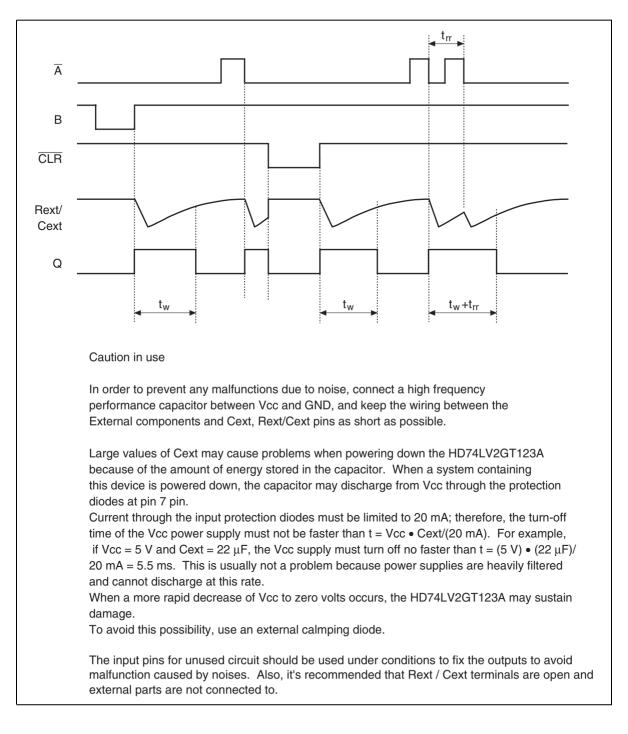
• $C_{L} = 50 \text{ pF}$

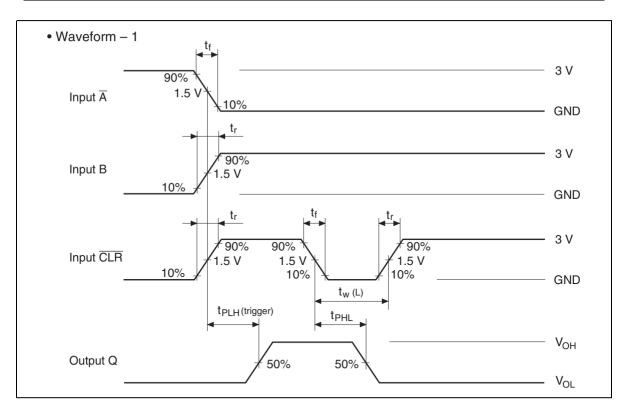
Item	Symbol	V_{cc} (V)	$T_a = 25^{\circ}C$			Unit	Test Conditions
			Min	Тур	Max	_	
Power dissipation capacitance	$C_{_{PD}}$	5.0	—	31.0	—	pF	f = 10 MHz

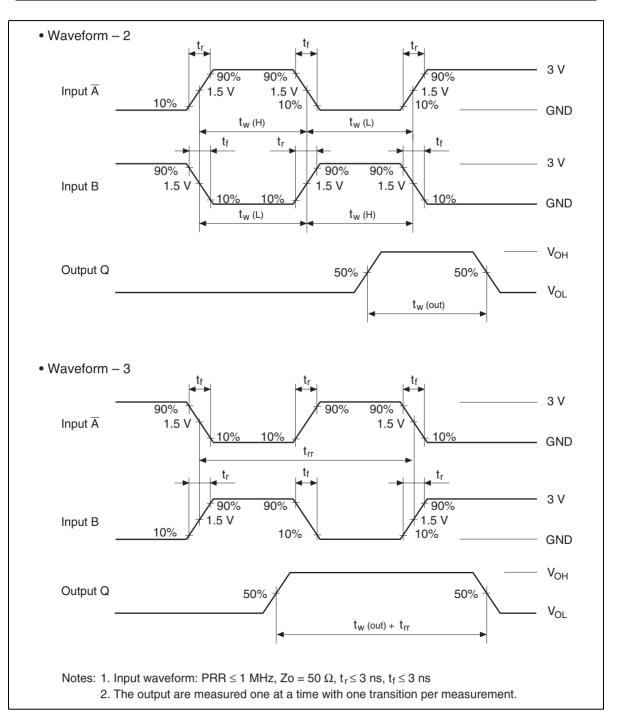
Test Circuit



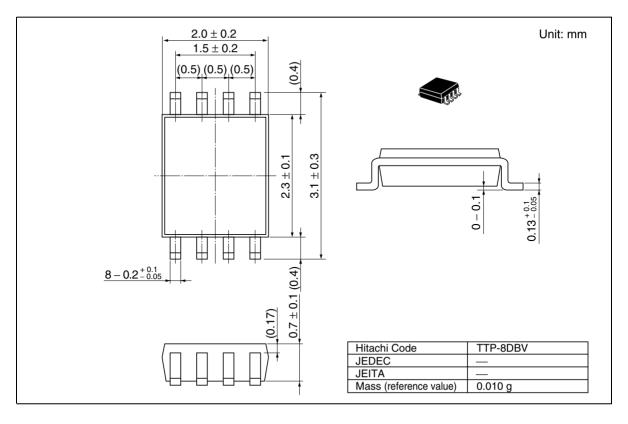
Timing Diagram







Package Dimensions



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